- 1024 X 8 Organization
- All Inputs and Outputs Fully TTL Compatible
- Static Operation (No Clocks, No Refresh)
- Max Access/Min Cycle Time

'2708-35 350 ns '2708-45 450 ns '27L08-45 450 ns

- 3-State Outputs for OR-Ties
- N-Channel Silicon-Gate Technology
- 8-Bit Output for Use in Microprocessor-Based Systems
- Power Dissipation

'27L08 '2708 580 mW Max Active 800 mW Max Active

- 10% Power Supply Tolerance (TMS27L08-45 and all SMJ' versions)
- Plug-Compatible Pin-Outs Allowing Interchangeability/Upgrade to 16K With Minimum Board Change
- Available in Full Military Temperature Range Versions (SMJ2708)

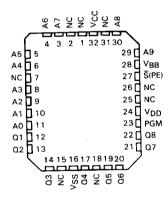
#### description

The '2708-35, '2708-45, and '27L08-45 are ultraviolet light-erasable, electrically programmable read-only memories. They have 8,192 bits organized as 1024 words of 8-bit length. The devices are fabricated using N-channel silicon-gate technology for high speed and simple interface with MOS and bipolar circuits. All inputs (including program data inputs) can be driven by Series 54/74 TTL circuits without the use of external pull-up resistors. Each output can drive one Series 54/74 or 54LS/74LS TTL circuit without external resistors. The '27L08 guarantees 200 mV dc noise immunity in the high state and 250 mV in the low state. The data outputs for the '2708-35, '2708-45, and '27L08-45 are three-state for OR-tying multiple devices on a common bus.

TMS2708 . . . JL PACKAGE SMJ2708 . . . J PACKAGE (TOP VIEW)

| A7 [ | <u> </u>   | J24 | ] Vcc            |
|------|------------|-----|------------------|
| A6   | 2          | 23  | 8A [             |
| A5   | 3          | 22  | ] A9             |
| A4   | 4          | 21  | ]∨ <sub>BB</sub> |
| A3   | 5          | 20  | S(PE)            |
| A2   | <b>□</b> 6 | 19  | OQV [            |
| Α1   | ٦,         | 18  | PGM              |
| AO   | ₫s         | 17  | 3 Q8             |
| Q1   | □9         | 16  | ] Q7             |
| 0.2  | □10        | 15  | ] Q6             |
| Q3   | ∐ու        | 14  | Q5               |
| Vss  | 12         | 13  | ] Q4             |

SMJ2708 . . . FE PACKAGE (TOP VIEW)



NC - No Connection

|       | PIN NOMENCLATURE           |
|-------|----------------------------|
| A0-A7 | Address Inputs             |
| NC    | No Connection              |
| PGM   | Program                    |
| Q1-Q8 | Data Out                   |
| S(PE) | Chip Select/Program Enable |
| ∨вв   | -5-V Power Supply          |
| Vcc   | +5-V Power Supply          |
| VDD   | + 12-V Power Supply        |
| VSS   | 0-V Ground                 |

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The SMJ' Series is offered in a 24-pin dual-in-line ceramic package (J) and also in a 32-pin leadless ceramic chip carrier (FE). The J package is designed for insertion in mounting-hole rows on 600-mil (15.2 mm) centers whereas the FE package is intended for surface mounting on solder pads on 0.05-inch (1.27 mm) centers. The FE package is a three-layer 32-pad rectangular chip carrier with dimensions of  $0.450 \times 0.550 \times 0.100$  inches (11.43  $\times$  13.97  $\times$  2.54 mm). This series is designed for operation from  $-55\,^{\circ}\text{C}$  to  $125\,^{\circ}\text{C}$ .

#### operation (read mode)

#### address (AO-A9)

The address-valid interval determines the device cycle time. The 10-bit positive-logic address is decoded on-chip to select one of the 1024 words of 8-bit length in the memory array. A0 is the least-significant bit and A9 is the most-significant bit of the word address.

#### chip select, program enable (\$\overline{S}\$ (PE)]

When the chip select is low, all eight outputs are enabled and the eight-bit addressed word can be read. When the chip select is high, all eight outputs are in a high-impedance state.

#### data out (Q1-Q8)

The chip must be selected before the eight-bit output word can be read. Data will remain valid until the address is changed or the chip is deselected. When deselected, the three-state outputs are in a high-impedance state. The outputs will drive TTL circuits without external components.

#### program

The program pin must be held below VCC in the read mode.

#### operation (program mode)

#### erase

Before programming, the '2708-35, '2708-45, or '27L08-45 is erased by exposing the chip through the transparent lid to high-intensity ultraviolet light that has a wavelength of 253.7 nanometers (2537 Angstroms). The recommended minimum exposure dose (UV intensity × exposure time) is fifteen watt-seconds per square centimeter. Thus, a typical 12 milliwatt per square centimeter, filterless UV lamp will erase the device in a minimum of 21 minutes. The lamp should be located about 2.5 centimeters (1 inch) above the chip during erasure. After erasure, all bits are in the high state.

### programming

Programming consists of successively depositing a small amount of charge to a selected memory cell that is to be changed from the erased high state to the low state. A low can be changed to a high only by erasure. Programming is normally accomplished on a PROM or EPROM Programmer, an example of which is TI's Universal PROM Programming Module in conjunction with the 990 prototyping system. Programming must be done at room temperature (25 °C) only.

# to start programming (see program cycle timing diagram)

First bring the  $\bar{S}$  (PE) pin to +12 V to disable the outputs and convert them to inputs. This pin is held high for the duration of the programming sequence. The first word to be programmed is addressed (it is customary to begin with the "0" address) and the data to be stored is placed on the Q1-Q8 program inputs. Then a +25 V program pulse is applied to the program pin. After 0.1 to 1.0 milliseconds the program pin is brought back to 0 V. After at least one microsecond the word address is sequentially changed to the next location, the new data is set up and the program pulse is applied.

**EPROM Devices** 

6

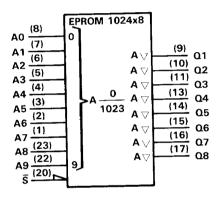
# 1024 WORD BY 8-BIT ERASABLE PROGRAMMABLE READ-ONLY MEMORIES

Programming continues in this manner until all words have been programmed. This constitutes one of N program loops. The entire sequence is then repeated N times with  $N \times t_W(PR) \ge 100$  ms. Thus, if  $t_W(PR) = 1$  ms; then N = 100, the minimum number of program loops required to program the EPROM.

#### to stop programming

After cycling through the N program loops, the last program pulse is brought to 0 V, then Program Enable [\$\overline{S}\$ (PE)] is brought to VIL which takes the device out of the program mode. The data supplied by the programmer must be removed before the address is changed since the program inputs are now data outputs and change of address could cause a voltage conflict on the output buffer. Q1-Q8 outputs are invalid up to 10 microseconds after the program enable pin is brought from VIH(PE) to VIL.

# logic symbol<sup>†</sup>



<sup>&</sup>lt;sup>†</sup>This symbol is in accordance with IEEE Std 91/ANSI Y32.14 and recent decisions in IEEE and IEC. See explanation on page 10-1.

# absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>‡</sup>

| Supply voltage, VBB (see Note 1)  |
|---|
| Supply voltage, VBB (see Note 1)  |
| Supply voltage, VCC (see Note 1)  |
| Supply voltage, VCC (see Note 1)  |
| Supply voltage, VDD (see Note 1) -0.3 V to 15 V Supply voltage, VSS (see Note 1) -0.3 V to 20 V |
| to the second (see Note 1)  |
| - N-4-1)  |
| to Voc  |
| TMS   |
|   |
| Operating case temperature range  |
| Storage temperature range   |

<sup>\$</sup> Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the "Recommended Operating Conditions" section of this specification is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: Under absolute maximum ratings, voltage values are with respect to the most-negative supply voltage. VBB (substrate), unless otherwise noted. Throughout the remainder of this data sheet, voltage values are with respect to VSS.



# recommended operating conditions

| PARAMETER  | TMS2708-35<br>TMS2708-45 |     |                     | TM   | UNIT |                     |     |
|--|--------------------------|-----|---------------------|------|------|---------------------|-----|
|  | MIN                      | NOM | MAX                 | MIN  | NOM  | MAX                 | 1   |
| Supply voltage, VBB  | -4.75                    | - 5 | - 5.25              | -4.5 | -5   | -5.5                | v   |
| Supply voltage, V <sub>CC</sub>  | 4.75                     | 5   | 5.25                | 4.5  | 5    | 5.5                 | l v |
| Supply voltage, V <sub>DD</sub>  | 11.4                     | 12  | 12.6                | 10.8 | 12   | 13.2                | l v |
| Supply voltage VSS   |                          | 0   |                     |      | 0    |                     | l · |
| High-level input voltage, V <sub>IH</sub><br>(except program and program enable)                                     | 2.4                      |     | V <sub>CC</sub> + 1 | 2.2  |      | V <sub>CC</sub> + 1 | _   |
| High-level program enable input voltage, VIH(PE)   | 11.4                     | 12  | 12.6                | 10.8 | 12   | 13.2                | V   |
| High-level program input voltage, VIH(PR)  | 25                       | 26  | 27                  | 25   | 26   | 27                  | v   |
| Low-level input voltage, VIL (except program)  | Vss                      |     | 0.65                | Vss  |      | 0.65                | v   |
| Low-level program input voltage, V <sub>IL</sub> (PR)<br>Note: V <sub>IL</sub> (PR) max ≤ V <sub>IH</sub> (PR) −25 V | VSS                      |     | 1                   | VSS  |      | 1                   | v   |
| High-level program pulse input current (sink), IH(PR)  |                          |     | 40                  |      |      | 40                  | mA  |
| Low-level program pulse input current (source), I <sub>IL</sub> (PR)   |                          |     | 3                   |      |      | 3                   | mA  |
| Operating free-air temperature, TA   | 0                        |     | 70                  | 0    |      | 70                  | °C  |

# electrical characteristics over full ranges of recommended operating conditions (unless otherwise noted)

| PARAMETER                                    |                                     | TEST CONDITIONS  | ı.  | MS2708           |      | TN  | 1S27L08          | 3-45 | UNIT     |
|--|-------------------------------------|--|-----|------------------|------|-----|------------------|------|----------|
|  |                                     |  | MIN | TYP <sup>†</sup> | MAX  | MIN | TYP <sup>†</sup> | MAX  | 1        |
| Vон  | High-level autput voltage           | l <sub>OH</sub> = -100 μA                                      | 3.7 | _                |      | 3.7 |                  |      | <u> </u> |
|  | - Ingrisorer datput voltage         | I <sub>OH</sub> = -1 mA  | 2.4 |                  |      | 2.4 |                  |      | \ V      |
| VOL  | Low-level output voltage            | I <sub>OL</sub> = 1.6 mA                                       |     |                  | 0.45 |     |                  | 0.40 | v        |
| <u> 11                                  </u> | Input current (leakage)             | $V_1 = 0 \ V \ to \ 5.25 \ V$                                  |     | 1                | 10   |     | 1                | 10   | μА       |
| 10   | Output current (leakage)            | $\overline{S}$ (PE) = 5 V,<br>V <sub>O</sub> = 0.4 V to 5.25 V |     | 1                | 10   |     | 1                | 10   | μΑ       |
| 1 <sub>BB</sub>                              | Supply current from VBB             | All inputs high,   |     | 30               | 45   |     | 9                | 18   | mA       |
| lcc  | Supply current from VCC             | $\overline{S}$ (PE) $\approx$ 5 V,                             |     | 6                | 10   |     | 0.9              | 6    | mA       |
| IDD  | Supply current from V <sub>DD</sub> | T <sub>A</sub> = °C<br>(worst case)                            |     | 50               | 65   |     | 20               | 34   | mA       |
|  |                                     | T <sub>A</sub> = 70°C  |     |                  | 800  |     |                  | 350  |          |
| PD(AV)                                       | Power Dissipation                   | $T_A = 0  ^{\circ}C,  \overline{S} = 0  V$                     |     |                  |      |     | 245              | 475  | mW       |
|  |                                     | $T_A = 0$ °C, $\overline{S} = +5$ V                            |     |                  |      |     | 290              | 580  |          |

# capacitance over recommended supply voltage range and operating free-air temperature range, $f = 1 \text{ MHz}^{\dagger}$

|                                   | <br>•            |     |      |
|-----------------------------------|------------------|-----|------|
| PARAMETER                         | <br>ΤΛ           | AS' |      |
|                                   | TYP <sup>‡</sup> | MAX | UNIT |
| C <sub>i</sub> Input capacitance  | - 4              | 6   | pF   |
| C <sub>O</sub> Output capacitance | 8                | 12  | pF   |

 $<sup>^{\</sup>dagger}$ This parameter is tested on sample basis only.

 $<sup>^{\</sup>ddagger}$ All typical values are at T<sub>A</sub> = 25 °C and nominal voltages.

# TMS2708, TMS27L08 1024-WORD BY 8-BIT ERASABLE PROGRAMMABLE READ-ONLY MEMORIES

# switching characteristics over recommended supply voltage range and operating free-air temperature range

|                    | PARAMETER                              | TEST CONDITIONS                 | TMS2 | 708-35  |          | 2708<br>27L08 | UNIT |  |
|--------------------|--|---------------------------------|------|---------|----------|---------------|------|--|
|                    | PANAMETEN                              |                                 | MIN  | MIN MAX |          | MAX           | 1    |  |
| • • • •            | Access time from Address               |                                 |      | 350     | <u> </u> | 450           | ns   |  |
| ta(A)              | Access time from S                     | $C_L = 100 pF$                  |      | 120     |          | 120           | ns   |  |
| t <sub>V</sub> (A) | Output data valid after address change | 1 Series 54/74 TTL load         | D    |         | 0        |               | ns   |  |
| <sup>t</sup> dis   | Output disable time <sup>†</sup>       | $t_{f(S)}$ , $t_{f(A)} = 20$ ns | 0    | 120     | 0        | 120           | ns   |  |
| t <sub>c(rd)</sub> | Read cycle time                        |                                 | 350  |         | 450      |               | ns   |  |

<sup>&</sup>lt;sup>†</sup>Value calculated from 0.5 volt delta to measured output level.

# recommended timing requirements for programming $T_A = 25\,^{\circ}\text{C}$

|                     |  | TM   | IS'  | UNIT |
|---------------------|--|------|------|------|
|                     | PARAMETER  | MIN  | MAX  | UNIT |
|                     | Pulse duration, program pulse                      | 0.1  | 1    | ms   |
| tw(PR)              | Transition times (except program pulse)            |      | 20   | ns   |
| t <sub>t</sub> (PR) | Transition times, program pulse                    | 50   | 2000 | ns   |
|                     | Address setup time                                 | 10   |      | μS   |
| t <sub>su(A)</sub>  | Data setup time                                    | 10   |      | μS   |
| t <sub>su(D)</sub>  | Program enable setup time                          | 10   |      | μS   |
| th(A)               | Address hold time                                  | 1000 | _    | ns   |
| th(DA)              | Address hold time after program input data stopped | 0    |      | ns   |
| th(DA)              | Data hold time                                     | 1000 |      | ns   |
| th(PE)              | Program enable hold time                           | 500  |      | ns   |
| tSLAX               | Delay time, S(PE) low to address change            | 0    |      | กร   |

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## recommended operating conditions

| PARAMETER  | SMJ2708-35<br>SMJ2708-45 |     |                     | sıv   | 3-45 | UNIT                |    |
|--|--------------------------|-----|---------------------|-------|------|---------------------|----|
|  | MIN                      | NOM | MAX                 | MIN   | NOM  | MAX                 | Í  |
| Supply voltage, VBB  | - 4.75                   | - 5 | - 5.25              | - 4.5 | - 5  | - 5.5               | V  |
| Supply voltage, V <sub>CC</sub>  | 4.75                     | 5   | 5.25                | 4.5   | 5    | 5.5                 | V  |
| Supply voltage, VDD  | 11.4                     | 12  | 12.6                | 10.8  | 12   | 13.2                | V  |
| Supply voltage VSS   |                          | 0   |                     |       | 0    |                     | V  |
| High-level input voltage, VIH  |                          |     |                     |       |      | _                   | ļ  |
| (except program and program enable   | 2.4                      |     | V <sub>CC</sub> + 1 | 2.2   |      | V <sub>CC</sub> + 1 |    |
| High-level program enable input voltage, VIH(PE)   | 11.4                     | 12  | 12.6                | 10.8  | 12   | 13.2                | V  |
| High-level program input voltage, VIH(PR)  | 25                       | 26  | 27                  | 25    | 26   | 27                  | V  |
| Low-level input voltage, VIL (except program)  | VSS                      |     | 0.65                | VSS   |      | 0.65                | V  |
| Low-level program input voltage, $V_{IL(PR)}$<br>Note: $V_{IL(PR)}$ max $\leq V_{IH(PR)} - 25 \text{ V}$ | Vss                      |     | 1                   | VSS   |      | 1                   | V  |
| High-level program pulsle input current (sink), I <sub>IH(PR)</sub>                                      |                          |     | 40                  |       |      | 40                  | mA |
| Low-level program pulse input current (source), I <sub>IL</sub> (PR)                                     |                          | -   | 3                   |       |      | 3                   | mA |
| Operating case temperature, TC   | - 55                     |     | 125                 | - 55  |      | 125                 | °C |

# electrical characteristics over full ranges of recommended operating conditions (unless otherwise noted)

| PARAMETER |                           | RAMETER TEST CONDITIONS                                       |     | SMJ2708-35<br>SMJ2708-45 |      |     | SMJ27L08-45      |      |     |
|-----------|---------------------------|---|-----|--------------------------|------|-----|------------------|------|-----|
|           |                           |   | MIN | TYP <sup>†</sup>         | MAX  | MIN | TYP <sup>†</sup> | MAX  | 1   |
| Voн       | High-level output voltage | $I_{OH} = -100  \mu A$  | 3.7 |                          |      | 3.7 |                  |      |     |
|           |                           | I <sub>OH</sub> = -1 mA                                       | 2.4 |                          |      | 2.4 |                  |      | \ V |
| VOL       | Low-level output voltage  | I <sub>OL</sub> = 1.6 mA                                      |     |                          | 0.45 |     |                  | 0.40 | V   |
| tį        | Input current (leakage)   | V <sub>I</sub> = 0 V to 5.25 V                                |     | 1                        | 10   |     | 1                | 10   | μА  |
| lo        | Output current (leakage)  | $\overline{S}$ (PE) = 5 V,<br>V <sub>O</sub> = 0.4 V to 5.5 V |     | 1                        | 10   |     | 1                | 10   | μΑ  |
| BB        | Supply current from VBB   |   | _   | 30                       | 45   |     | 9                | 18   | mA  |
| Icc       | Supply current from VCC   | All inputs high,  |     | 6                        | 10   |     | 0.9              | 6    | mA  |
| IDD       | Supply current from VDD   | S̄ (PE) ≈ 5 V,  |     | 50                       | 65   |     | 20               | 34   | mA  |

# capacitance over recommended supply voltage range and operating case temperature range, $f=1\,\text{MHz}^{\dagger}$

|    | PARAMETER          |     | SMJ'  |      |
|----|--------------------|-----|-------|------|
|    | PANAMETER          | TYP | ‡ MAX | UNIT |
| Ci | Input capacitance  | 4   | 6     | pF   |
| Co | Output capacitance | 8   | 12    | pF   |

 $<sup>\</sup>ensuremath{^{\dagger}}\xspace$  This parameter is tested on sample basis only.

 $<sup>^{\</sup>ddagger}All$  typical values are at T  $_{C}~=~25\,^{o}C$  and nominal voltages.

# SMJ2708, SMJ27L08 1024-WORD BY 8-BIT ERASABLE PROGRAMMABLE READ-ONLY MEMORIES

# switching characteristics over recommended supply voltage range and operating case temperature range

| PARAMETER          |  | METER TEST CONDITIONS                   |     | 708-35 | SMJ | UNIT |    |
|--------------------|--|---|-----|--------|-----|------|----|
|                    |  |   | MIN | MAX    | MIN | MAX  |    |
| t <sub>a(A)</sub>  | Access time from Address               |   |     | 350    |     | 450  | ns |
| ta(S)              | Access time from \$\overline{S}\$      | $C_L = 100 pF$                          |     | 120    |     | 120  | ns |
| t <sub>v(A)</sub>  | Output data valid after address change | 1 Series 54/74 TTL load                 | 0   |        | 0   |      | ns |
| tdis               | Output disable time <sup>†</sup>       | $t_{f(S)}$ , $t_{f(A)} = 20 \text{ ns}$ | 0   | 120    | 0   | 120  | ns |
| t <sub>c(rd)</sub> | Read cycle time                        |   | 350 |        | 450 |      | ns |

<sup>&</sup>lt;sup>†</sup>Value calculated from 0.5 volt delta to measured output level.

# recommended timing requirements for programming $T_C = 25\,^{\circ}C$

|                     | PARAMETER  | SI   | SMJ' |      |
|---------------------|--|------|------|------|
|                     |  | MIN  | MAX  | UNIT |
| tw(PR)              | Pulse duration, program pulse                      | 0.1  | 1    | ms   |
| t <sub>t</sub>      | Transition times (except program pulse)            |      | 20   | ns   |
| t <sub>t</sub> (PR) | Transition times, program pulse                    | 50   | 2000 | ns   |
| t <sub>su(A)</sub>  | Address setup time                                 | 10   |      | μS   |
| t <sub>su(D)</sub>  | Data setup time                                    | 10   |      | μS   |
| t <sub>su(PE)</sub> | Program enable setup time                          | 10   |      | μS   |
| th(A)               | Address hold time                                  | 1000 |      | ns   |
| th(DA)              | Address hold time after program input data stopped | 0    |      | ns   |
| th(D)               | Data hold time                                     | 1000 |      | ns   |
| th(PE)              | Program enable hold time                           | 500  |      | ns   |
| †SLAX               | Delay time, S(PE) low to address change            | 0    |      | ns   |

#### PARAMETER MEASUREMENT INFORMATION

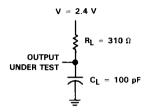
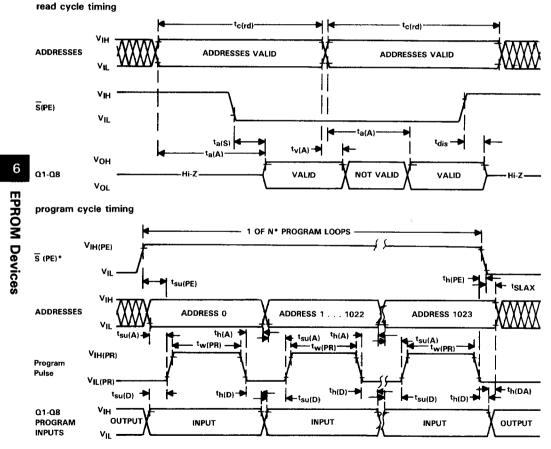


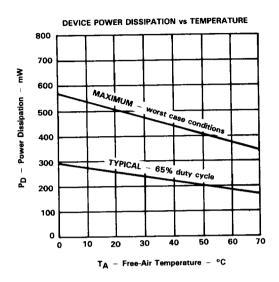
FIGURE 1 - TYPICAL OUTPUT LOAD CIRCUIT

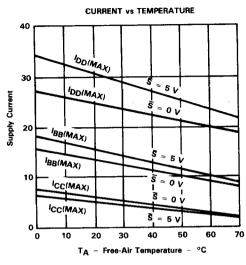


\*§ (PE) is at +12 V through N program loops where N <100 ms/tw (PR). NOTE: Q1-Q8 outputs are invalid up to 10 µsec after programming [§ (PE) goes low). All timing reference points in this data sheet (inputs and outputs) are 90% points.

IEXAS ISTRUMENTS

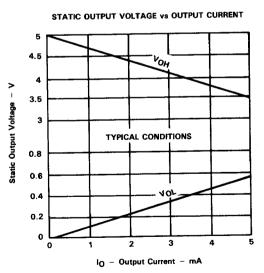
#### TYPICAL '27L08-45 CHARACTERISTICS

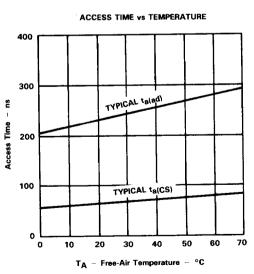




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